

FEATURES

- **Guaranteed Low Offset Voltage**

LT1001AM	15 μ V max
LT1001C	60 μ V max
- **Guaranteed Low Drift**

LT1001AM	0.6 μ V/ $^{\circ}$ C max
LT1001C	1.0 μ V/ $^{\circ}$ C max
- **Guaranteed Low Bias Current**

LT1001AM	2nA max
LT1001C	4nA max
- **Guaranteed CMRR**

LT1001AM	114dB min
LT1001C	110dB min
- **Guaranteed PSRR**

LT1001AM	110dB min
LT1001C	106dB min
- **Low Power Dissipation**

LT1001AM	75mW max
LT1001C	80mW max
- **Low Noise** 0.3 μ V_{P-P}

APPLICATIONS

- Thermocouple amplifiers
- Strain gauge amplifiers
- Low level signal processing
- High accuracy data acquisition

DESCRIPTION

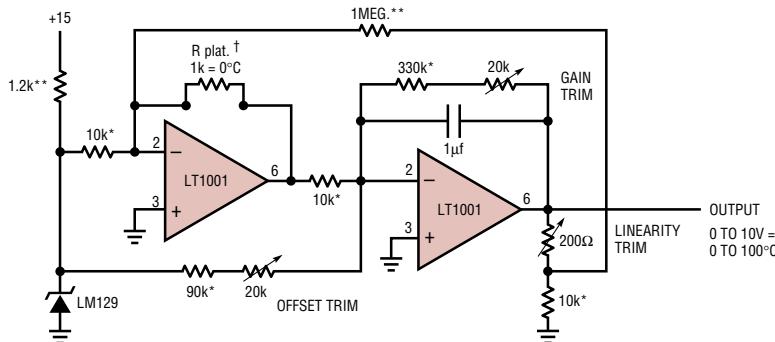
The LT®1001 significantly advances the state-of-the-art of precision operational amplifiers. In the design, processing, and testing of the device, particular attention has been paid to the optimization of the entire distribution of several key parameters. Consequently, the specifications of the lowest cost, commercial temperature device, the LT1001C, have been dramatically improved when compared to equivalent grades of competing precision amplifiers.

Essentially, the input offset voltage of all units is less than 50 μ V (see distribution plot below). This allows the LT1001AM/883 to be specified at 15 μ V. Input bias and offset currents, common-mode and power supply rejection of the LT1001C offer guaranteed performance which were previously attainable only with expensive, selected grades of other devices. Power dissipation is nearly halved compared to the most popular precision op amps, without adversely affecting noise or speed performance. A beneficial by-product of lower dissipation is decreased warm-up drift. Output drive capability of the LT1001 is also enhanced with voltage gain guaranteed at 10mA of load current. For similar performance in a dual precision op amp, with guaranteed matching specifications, see the LT1002. Shown below is a platinum resistance thermometer application.

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TYPICAL APPLICATION

Linearized Platinum Resistance Thermometer
with $\pm 0.025^{\circ}$ C Accuracy Over 0 to 100 $^{\circ}$ C



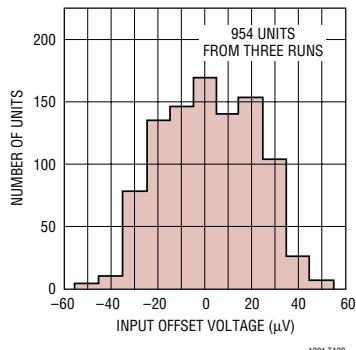
* ULTRONIX 105A WIREWOUND

** 1% FILM

† PLATINUM RTD
118MF (ROSEMOUNT, INC.)

‡ Trim sequence: trim offset (0° C = 1000.0 Ω), trim linearity (35° C = 1138.7 Ω), trim gain (100° C = 1392.6 Ω). Repeat until all three points are fixed with $\pm 0.025^{\circ}$ C.

Typical Distribution
of Offset Voltage
 $V_S = \pm 15V, T_A = 25^{\circ}$ C



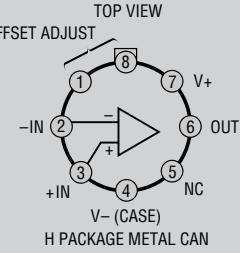
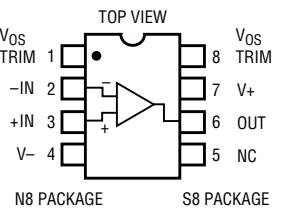
ABSOLUTE MAXIMUM RATINGS

(Note 1)

Supply Voltage	$\pm 22\text{V}$
Differential Input Voltage	$\pm 30\text{V}$
Input Voltage	$\pm 22\text{V}$
Output Short Circuit Duration	Indefinite

Operating Temperature Range

LT1001AM/LT1001M (OBSOLETE) .. -55°C to 150°C LT1001AC/LT1001C .. 0°C to 125°C Storage: All Devices .. -65°C to 150°C Lead Temperature (Soldering, 10 sec.) .. 300°C **PACKAGE/ORDER INFORMATION**

TOP VIEW  H PACKAGE METAL CAN $T_{JMAX} = 150^\circ\text{C}, \theta_{JA} = 150^\circ\text{C/W}, \theta_{JC} = 45^\circ\text{C/W}$	ORDER PART NUMBER	 N8 PACKAGE 8 PIN PLASTIC DIP  S8 PACKAGE 8 PIN PLASTIC SO $T_{JMAX} = 150^\circ\text{C}, \theta_{JA} = 130^\circ\text{C/W (N)}$ $T_{JMAX} = 150^\circ\text{C}, \theta_{JA} = 150^\circ\text{C/W (S)}$	ORDER PART NUMBER
	LT1001AMH/883		LT1001ACN8
	LT1001MH		LT1001CN8
	LT1001ACH		LT1001CS8
	LT1001CH		S8 PART MARKING 1001
OBsolete PACKAGE Consider the N8 and S8 Packages for Alternate Source	J8 PACKAGE 8 PIN HERMETIC DIP $T_{JMAX} = 150^\circ\text{C}, \theta_{JA} = 100^\circ\text{C/W (J)}$	OBsolete PACKAGE Consider the N8 and S8 Packages for Alternate Source	ORDER PART NUMBER
	LT1001AMJ8/883		
	LT1001MJ8		
	LT1001ACJ8 LT1001CJ8		

Consult LTC Marketing for parts specified with wider operating temperature ranges.

ELECTRICAL CHARACTERISTICSThe ● denotes the specifications which apply over the full operating temperature range, otherwise specifications are at $T_A = 25^\circ\text{C}$. $V_S = \pm 15\text{V}$, unless otherwise noted

SYMBOL	PARAMETER	CONDITIONS			LT1001AM/883			LT1001AC			LT1001M/LT1001C			UNITS
		Note 2	LT1001AM/883		MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	
V_{OS}	Input Offset Voltage				7	15		18	60		μV			
					10	25								
ΔV_{OS} ΔT_{Time}	Long Term Input Offset Voltage Stability	Notes 3 and 4			0.2	1.0		0.3	1.5		$\mu\text{V/month}$			
I_{OS}	Input Offset Current				0.3	2.0		0.4	3.8		nA			
I_b	Input Bias Current				± 0.5	± 2.0		± 0.7	± 4.0		nA			
e_n	Input Noise Voltage	0.1Hz to 10Hz (Note 3)			0.3	0.6		0.3	0.6		$\mu\text{V}_{\text{p-p}}$			
e_n	Input Noise Voltage Density	$f_0 = 10\text{Hz}$ (Note 6) $f_0 = 1000\text{Hz}$ (Note 3)			10.3	18.0		10.5	18.0		$\text{nV}\sqrt{\text{Hz}}$			
					9.6	11.0		9.8	11.0		$\text{nV}\sqrt{\text{Hz}}$			
A_{VOL}	Large Signal Voltage Gain	$R_L \geq 2\text{k}\Omega, V_0 = \pm 12\text{V}$ $R_L \geq 1\text{k}\Omega, V_0 = \pm 10\text{V}$			450	800		400	800		V/mV			
					300	500		250	500		V/mV			
CMRR	Common Mode Rejection Ratio	$V_{CM} = \pm 13\text{V}$			114	126		110	126		dB			
PSRR	Power Supply Rejection Ratio	$V_S = \pm 3\text{V}$ to $\pm 18\text{V}$			110	123		106	123		dB			
R_{in}	Input Resistance Differential Mode				30	100		15	80		$\text{M}\Omega$			

1001fb

ELECTRICAL CHARACTERISTICS

The ● denotes the specifications which apply over the full operating temperature range, otherwise specifications are at $T_A = 25^\circ\text{C}$. $V_S = \pm 15\text{V}$, $T_A = 25^\circ\text{C}$, unless otherwise noted

SYMBOL	PARAMETER	CONDITIONS	LT1001AM/883			LT1001M/LT1001C			UNITS
			MIN	TYP	MAX	MIN	TYP	MAX	
	Input Voltage Range		±13	±14		±13	±14		V
V_{OUT}	Maximum Output Voltage Swing	$R_L \geq 2\text{k}\Omega$ $R_L \geq 1\text{k}\Omega$	±13	±14		±13	±14		V
S_R	Slew Rate	$R_L \geq 2\text{k}\Omega$ (Note 5)	0.1	0.25		0.1	0.25		$\text{V}/\mu\text{s}$
GBW	Gain-Bandwidth Product	(Note 5)	0.4	0.8		0.4	0.8		MHz
P_d	Power Dissipation	No load No load, $V_S = \pm 3\text{V}$	46	75		48	80		mW
			4	6		4	8		mW

$V_S = \pm 15\text{V}$, $-55^\circ\text{C} \leq T_A \leq 125^\circ\text{C}$, unless otherwise noted

SYMBOL	PARAMETER	CONDITIONS	LT1001AM/883			LT1001M			UNITS
			MIN	TYP	MAX	MIN	TYP	MAX	
V_{OS}	Input Offset Voltage		●	30	60		45	160	μV
ΔV_{OS} ΔTemp	Average Offset Voltage Drift		●	0.2	0.6		0.3	1.0	$\mu\text{V}/^\circ\text{C}$
I_{OS}	Input Offset Current		●	0.8	4.0		1.2	7.6	nA
I_B	Input Bias Current		●	±1.0	±4.0		±1.5	±8.0	nA
A_{VOL}	Large Signal Voltage Gain	$R_L \geq 2\text{k}\Omega$, $V_0 = \pm 10\text{V}$	●	300	700		200	700	V/mV
CMRR	Common Mode Rejection Ratio	$V_{\text{CM}} = \pm 13\text{V}$	●	110	122		106	120	dB
PSRR	Power Supply Rejection Ratio	$V_S = \pm 3$ to $\pm 18\text{V}$	●	104	117		100	117	dB
	Input Voltage Range		●	±13	±14		±13	±14	V
V_{OUT}	Output Voltage Swing	$R_L \geq 2\text{k}\Omega$	●	±12.5	±13.5		±12.0	±13.5	V
P_d	Power Dissipation	No load	●	55	90		60	100	mW

$V_S = \pm 15\text{V}$, $0^\circ\text{C} \leq T_A \leq 70^\circ\text{C}$, unless otherwise noted

SYMBOL	PARAMETER	CONDITIONS	LT1001AC			LT1001C			UNITS
			MIN	TYP	MAX	MIN	TYP	MAX	
V_{OS}	Input Offset Voltage		●	20	60		30	110	μV
ΔV_{OS} ΔTemp	Average Offset Voltage Drift		●	0.2	0.6		0.3	1.0	$\mu\text{V}/^\circ\text{C}$
I_{OS}	Input Offset Current		●	0.5	3.5		0.6	5.3	nA
I_B	Input Bias Current		●	±0.7	±3.5		±1.0	±5.5	nA
A_{VOL}	Large Signal Voltage Gain	$R_L \geq 2\text{k}\Omega$, $V_0 = \pm 10\text{V}$	●	350	750		250	750	V/mV
CMRR	Common Mode Rejection Ratio	$V_{\text{CM}} = \pm 13\text{V}$	●	110	124		106	123	dB
PSRR	Power Supply Rejection Ratio	$V_S = \pm 3\text{V}$ to $\pm 18\text{V}$	●	106	120		103	120	dB
	Input Voltage Range		●	±13	±14		±13	±14	V
V_{OUT}	Output Voltage Swing	$R_L \geq 2\text{k}\Omega$	●	±12.5	±13.8		±12.5	±13.8	V
P_d	Power Dissipation	No load	●	50	85		55	90	mW

Note 1: Absolute Maximum Ratings are those values beyond which the life of a device may be impaired.

Note 2: Offset voltage for the LT1001AM/883 and LT1001AC are measured after power is applied and the device is fully warmed up. All other grades are measured with high speed test equipment, approximately 1 second after power is applied. The LT1001AM/883 receives 168 hr. burn-in at 125°C . or equivalent.

Note 3: This parameter is tested on a sample basis only.

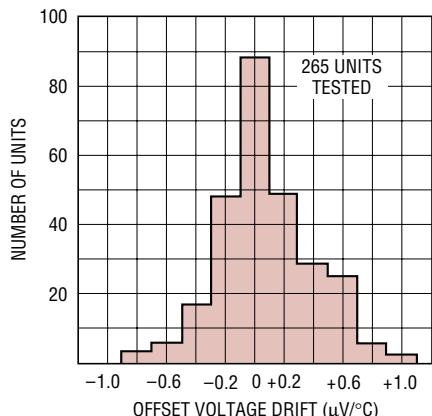
Note 4: Long Term Input Offset Voltage Stability refers to the averaged trend line of V_{OS} versus Time over extended periods after the first 30 days of operation. Excluding the initial hour of operation, changes in V_{OS} during the first 30 days are typically $2.5\mu\text{V}$.

Note 5: Parameter is guaranteed by design.

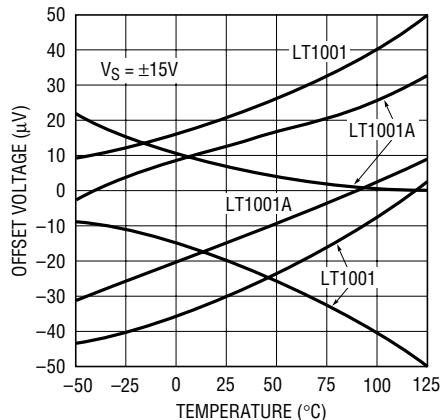
Note 6: 10Hz noise voltage density is sample tested on every lot. Devices 100% tested at 10Hz are available on request.

TYPICAL PERFORMANCE CHARACTERISTICS

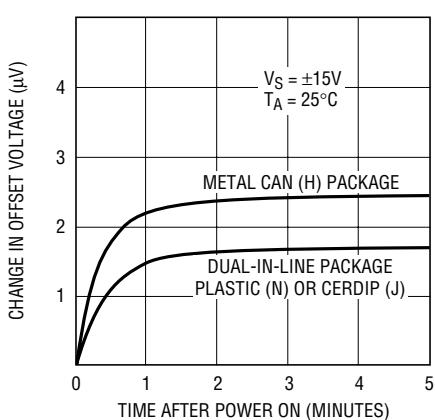
Typical Distribution of Offset Voltage Drift with Temperature



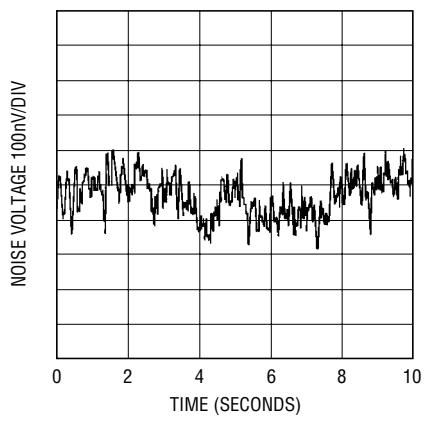
Offset Voltage Drift with Temperature of Representative Units



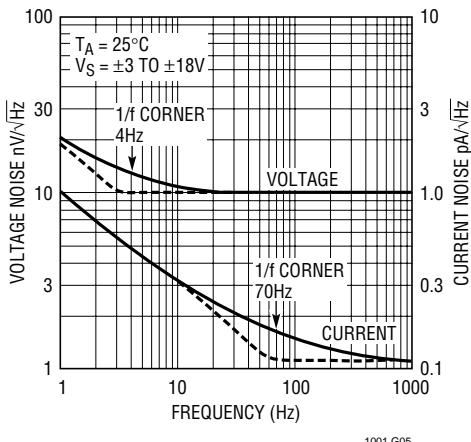
Warm-Up Drift



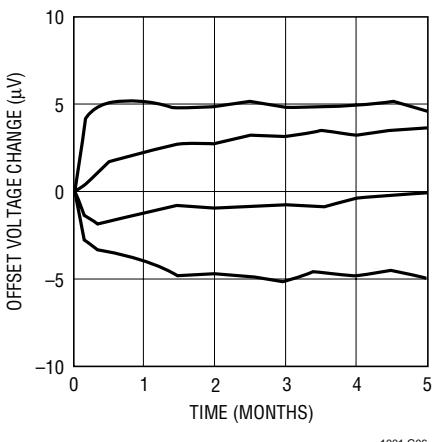
0.1Hz to 10Hz Noise



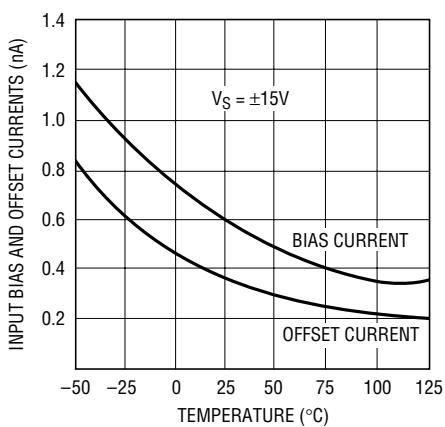
Noise Spectrum



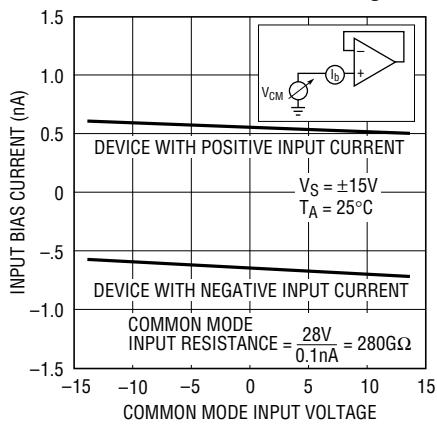
Long Term Stability of Four Representative Units



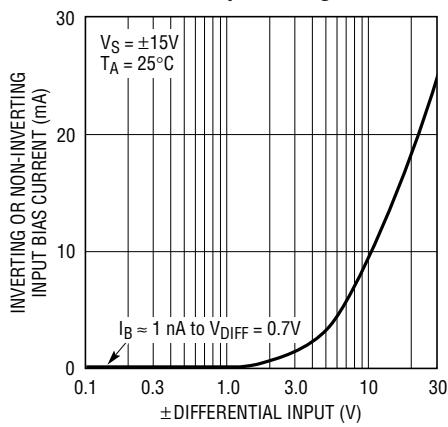
Input Bias and Offset Current vs Temperature



Input Bias Current Over the Common Mode Range

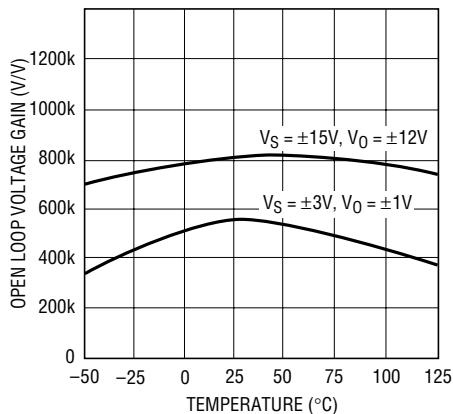


Input Bias Current vs Differential Input Voltage

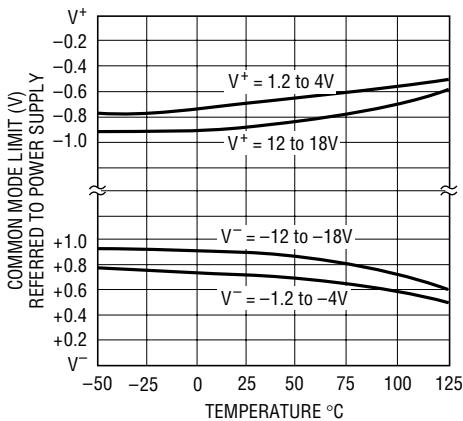


TYPICAL PERFORMANCE CHARACTERISTICS

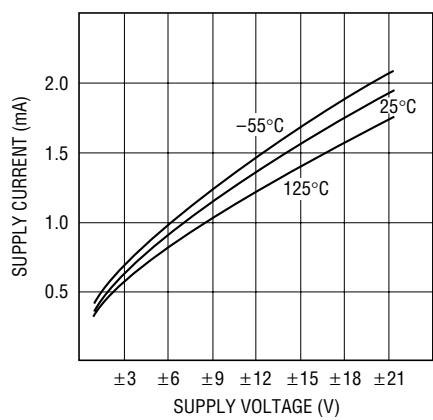
Open Loop Voltage Gain vs Temperature



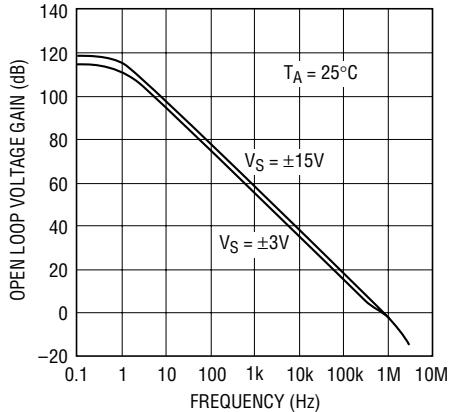
Common Mode Limit vs Temperature



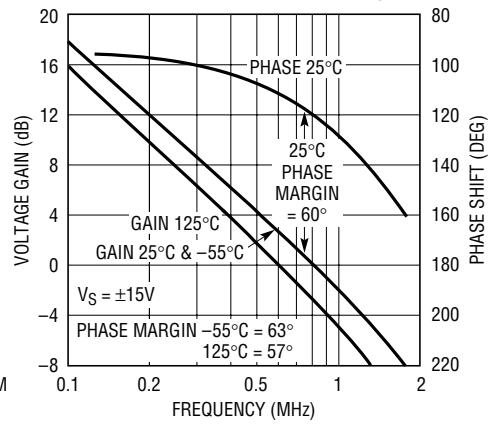
Supply Current vs Supply Voltage



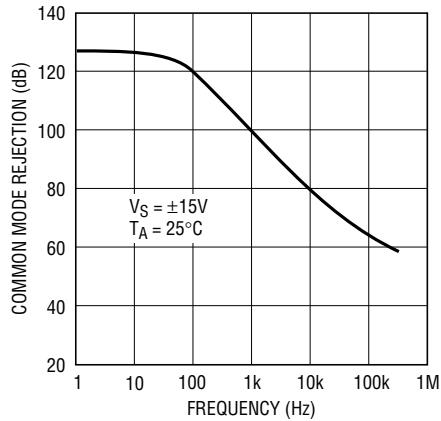
Open Loop Voltage Gain Frequency Response



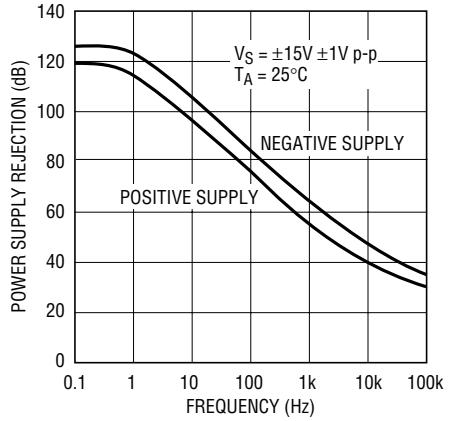
Gain, Phase Shift vs Frequency



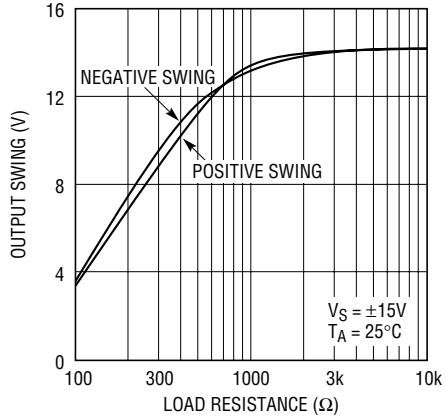
Common Mode Rejection Ratio vs Frequency



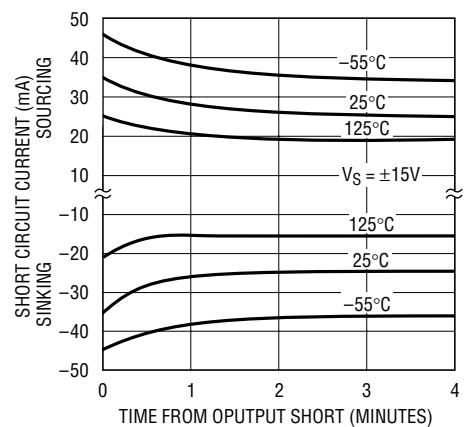
Power Supply Rejection Ratio vs Frequency



Output Swing vs Load Resistance

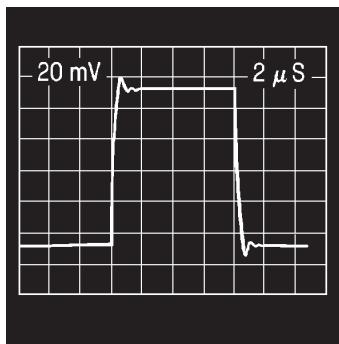


Output Short-Circuit Current vs Time



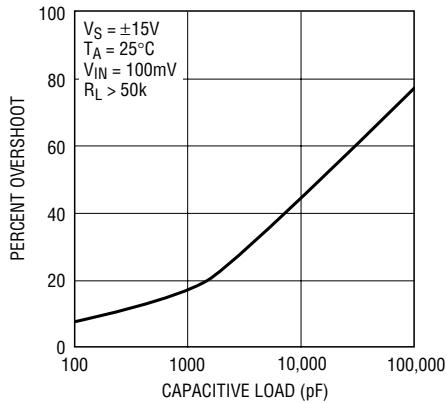
TYPICAL PERFORMANCE CHARACTERISTICS

Small Signal Transient Response

 $A_V = +1, C_L = 50\text{pF}$

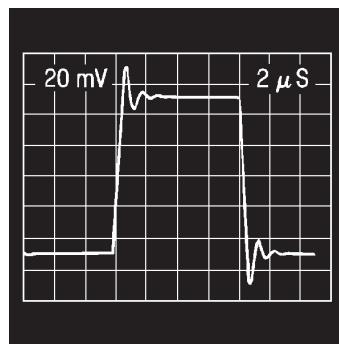
1001 G19

Voltage Follower Overshoot vs Capacitive Load



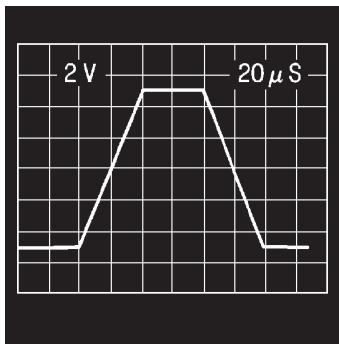
1001 G20

Small Signal Transient Response

 $A_V = +1, C_L = 1000\text{pF}$

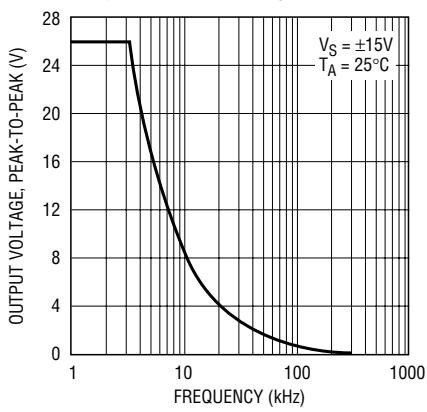
1001 G21

Large Signal Transient Response



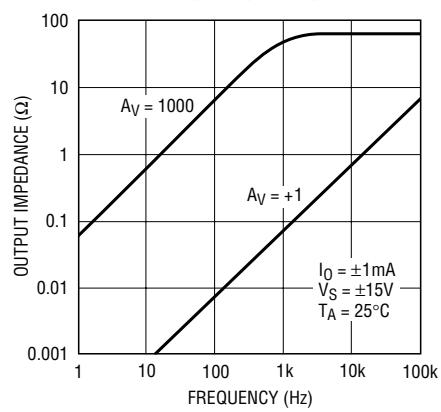
1001 G22

Maximum Undistorted Output vs. Frequency



1001 G23

Closed Loop Output Impedance



1001 G24

APPLICATIONS INFORMATION

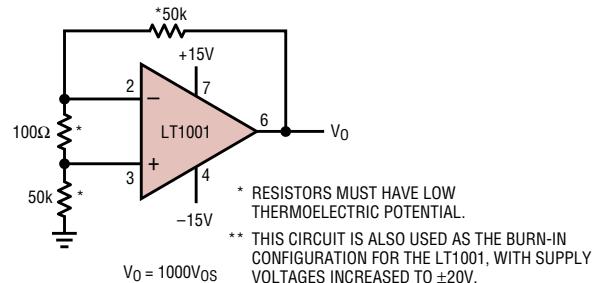
Application Notes and Test Circuits

The LT1001 series units may be inserted directly into OP-07, OP-05, 725, 108A or 101A sockets with or without removal of external frequency compensation or nulling components. The LT1001 can also be used in 741, LF156 or OP-15 applications provided that the nulling circuitry is removed.

The LT1001 is specified over a wide range of power supply voltages from $\pm 3\text{V}$ to $\pm 18\text{V}$. Operation with lower supplies is possible down to $\pm 1.2\text{V}$ (two Ni-Cad batteries). However, with $\pm 1.2\text{V}$ supplies, the device is stable only in closed loop gains of +2 or higher (or inverting gain of one or higher).

Unless proper care is exercised, thermocouple effects caused by temperature gradients across dissimilar metals at the contacts to the input terminals, can exceed the inherent drift of the amplifier. Air currents over device leads should be minimized, package leads should be short, and the two input leads should be as close together as possible and maintained at the same temperature.

Test Circuit for Offset Voltage and its Drift with Temperature

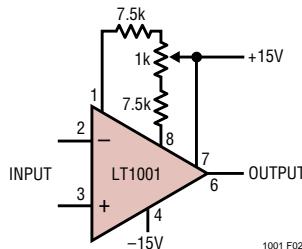
1001 F01
1001fb

APPLICATIONS INFORMATION

Offset Voltage Adjustment

The input offset voltage of the LT1001, and its drift with temperature, are permanently trimmed at wafer test to a low level. However, if further adjustment of V_{OS} is necessary, nulling with a 10k or 20k potentiometer will not degrade drift with temperature. Trimming to a value other than zero creates a drift of $(V_{OS}/300)\mu V/\text{ }^{\circ}\text{C}$, e.g., if V_{OS} is

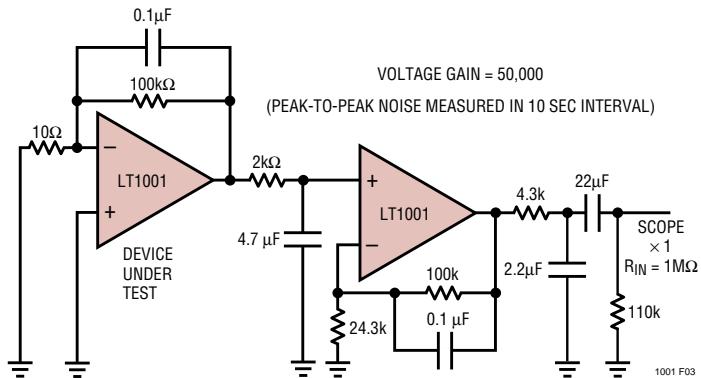
Improved Sensitivity Adjustment



1001 F02

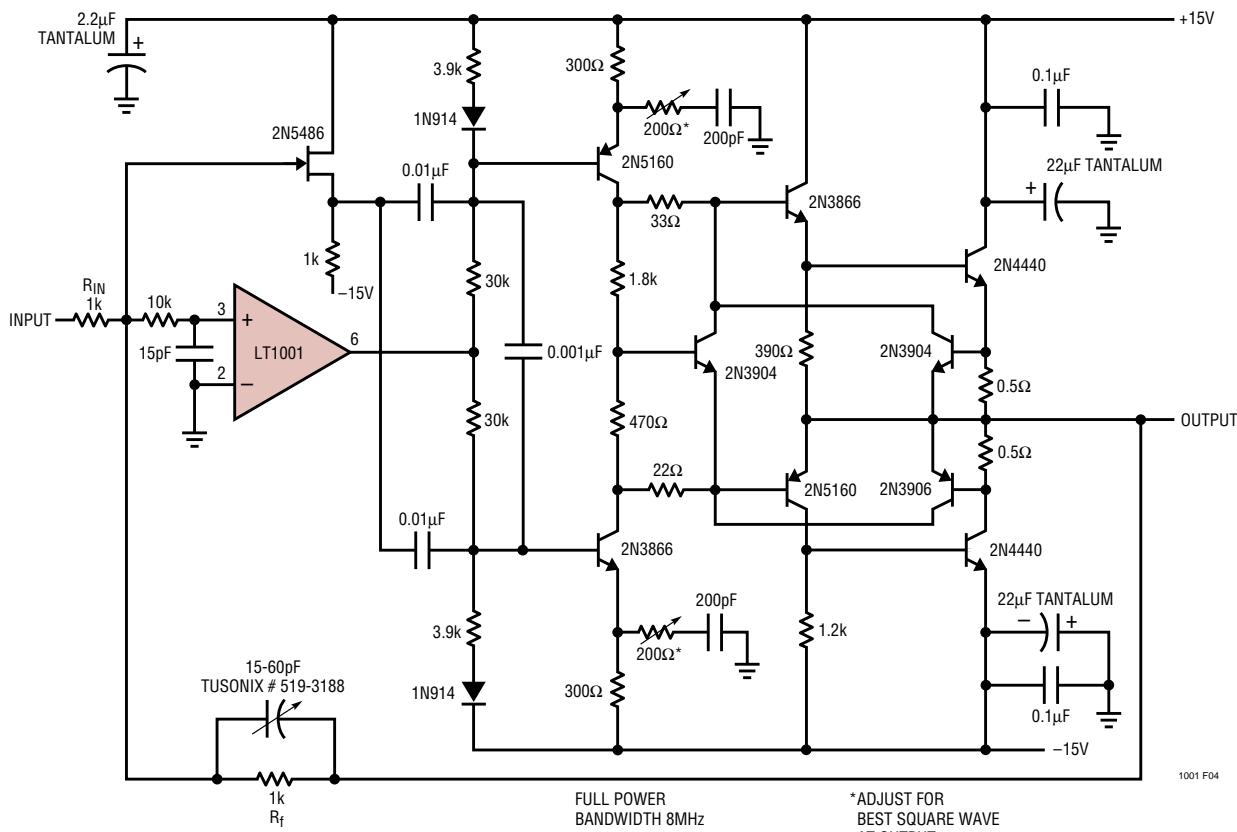
adjusted to 300 μV , the change in drift will be $1 \mu\text{V}/\text{ }^{\circ}\text{C}$. The adjustment range with a 10k or 20k pot is approximately $\pm 2.5\text{mV}$. If less adjustment range is needed, the sensitivity and resolution of the nulling can be improved by using a smaller pot in conjunction with fixed resistors. The example below has an approximate null range of $\pm 100 \mu\text{V}$.

0.1Hz to 10Hz Noise Test Circuit



The device under test should be warmed up for three minutes and shielded from air currents.

DC Stabilized 1000v/ μsec Op Amp



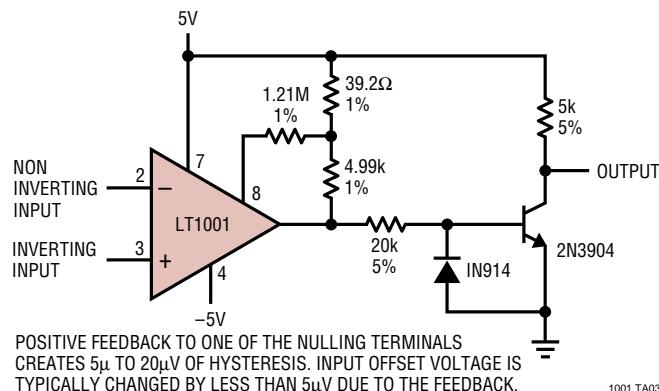
FULL POWER
BANDWIDTH 8MHz

*ADJUST FOR
BEST SQUARE WAVE
AT OUTPUT

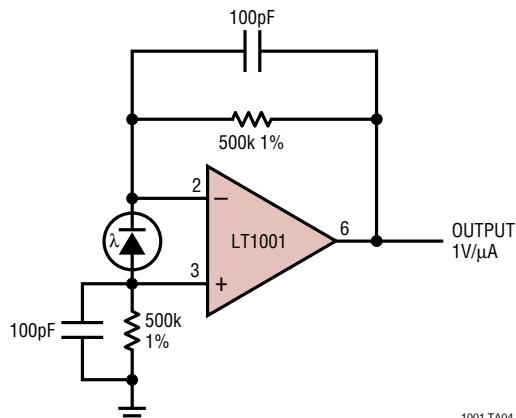
1001 F04

TYPICAL APPLICATIONS

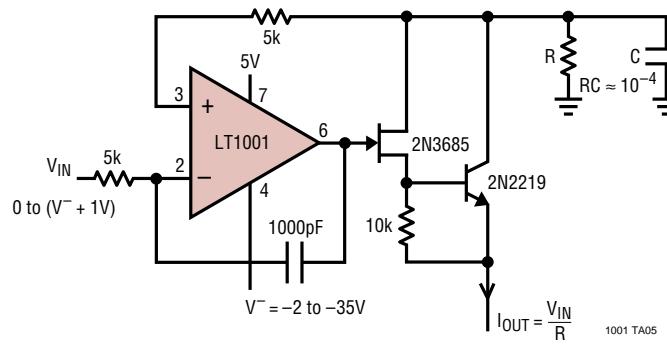
Microvolt Comparator with TTL Output



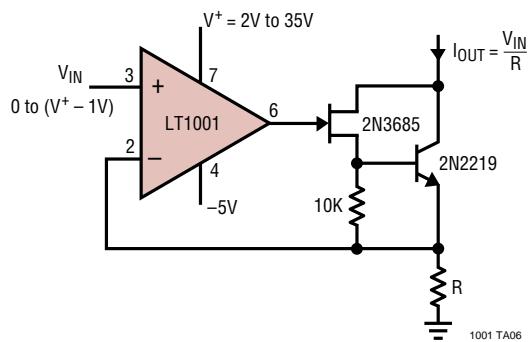
Photodiode Amplifier



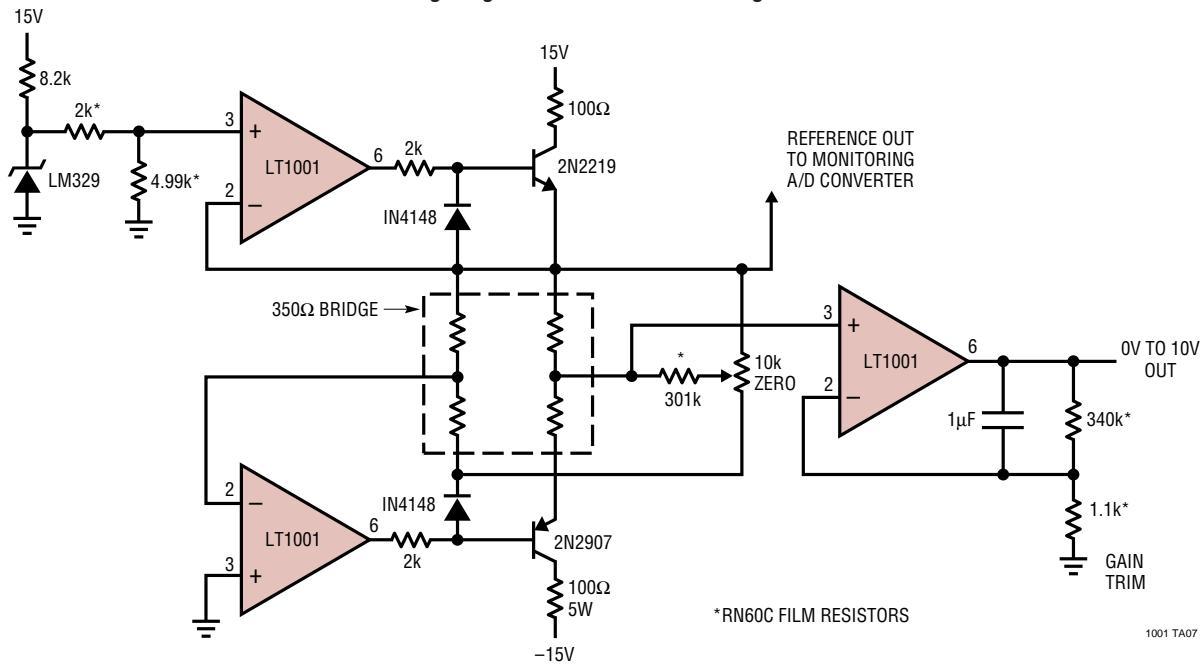
Precision Current Source



Precision Current Sink

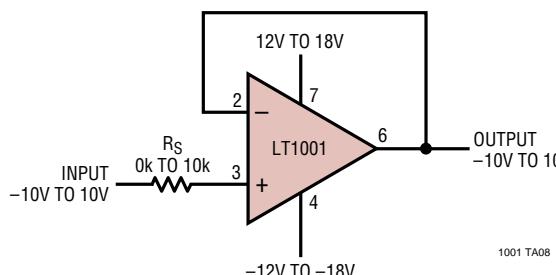


Strain Gauge Signal Conditioner with Bridge Excitation



TYPICAL APPLICATIONS

Large Signal Voltage Follower With 0.001% Worst Case Accuracy

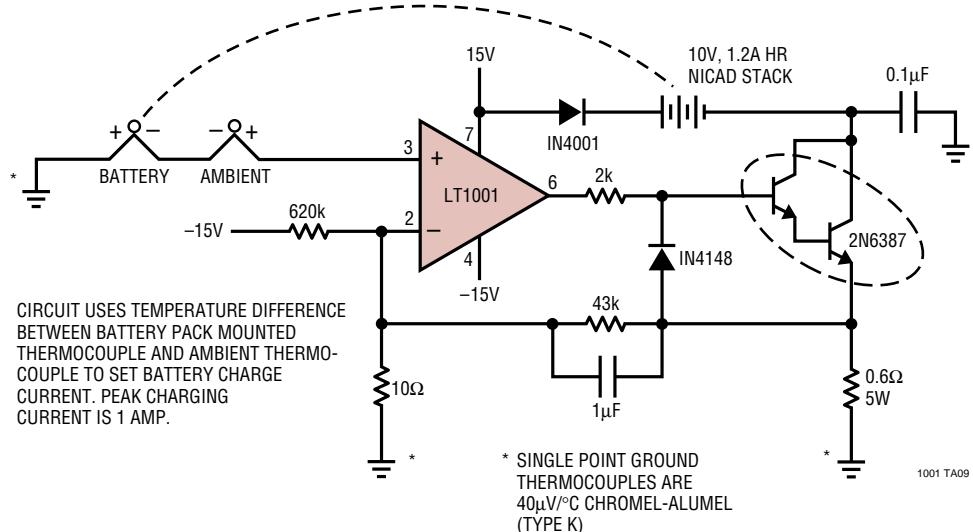


The voltage follower is an ideal example illustrating the overall excellence of the LT1001. The contributing error terms are due to offset voltage, input bias current, voltage gain, common mode and power-supply

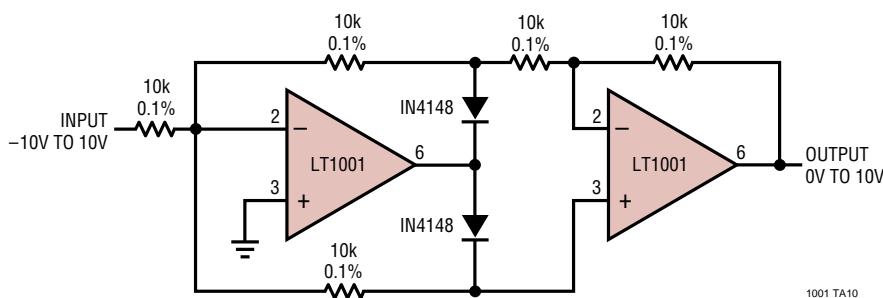
rejections. Worst-case summation of guaranteed specifications is tabulated below.

Error	OUTPUT ACCURACY			
	LT1001AM /883	LT1001C	LT1001AM /883	LT1001C
	25°C Max.	25°C Max.	-55 to 125°C Max.	0 to 70°C Max.
Offset Voltage	15µV	60µV	60µV	110µV
Bias Current	20µV	40µV	40µV	55µV
Common Mode Rejection	20µV	30µV	30µV	50µV
Power Supply Rejection	18µV	30µV	36µV	42µV
Voltage Gain	22µV	25µV	33µV	40µV
Worst-case Sum	95µV	185µV	199µV	297µV
Percent of Full Scale (=20V)	0.0005%	0.0009%	0.0010%	0.0015%

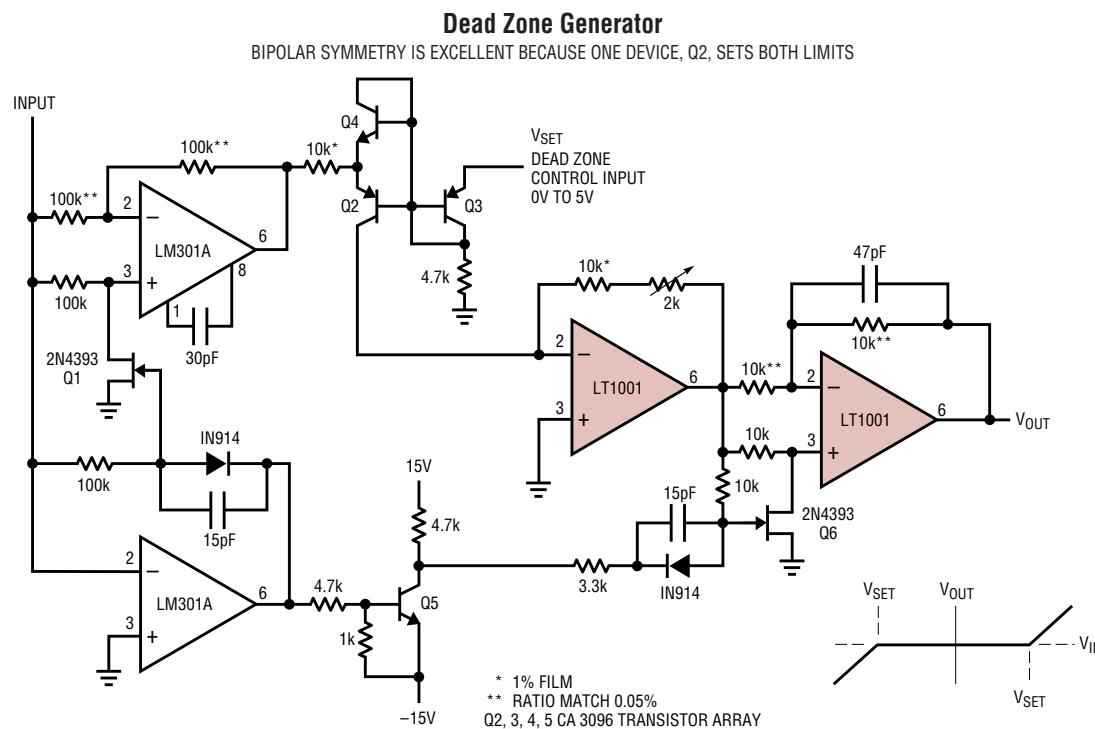
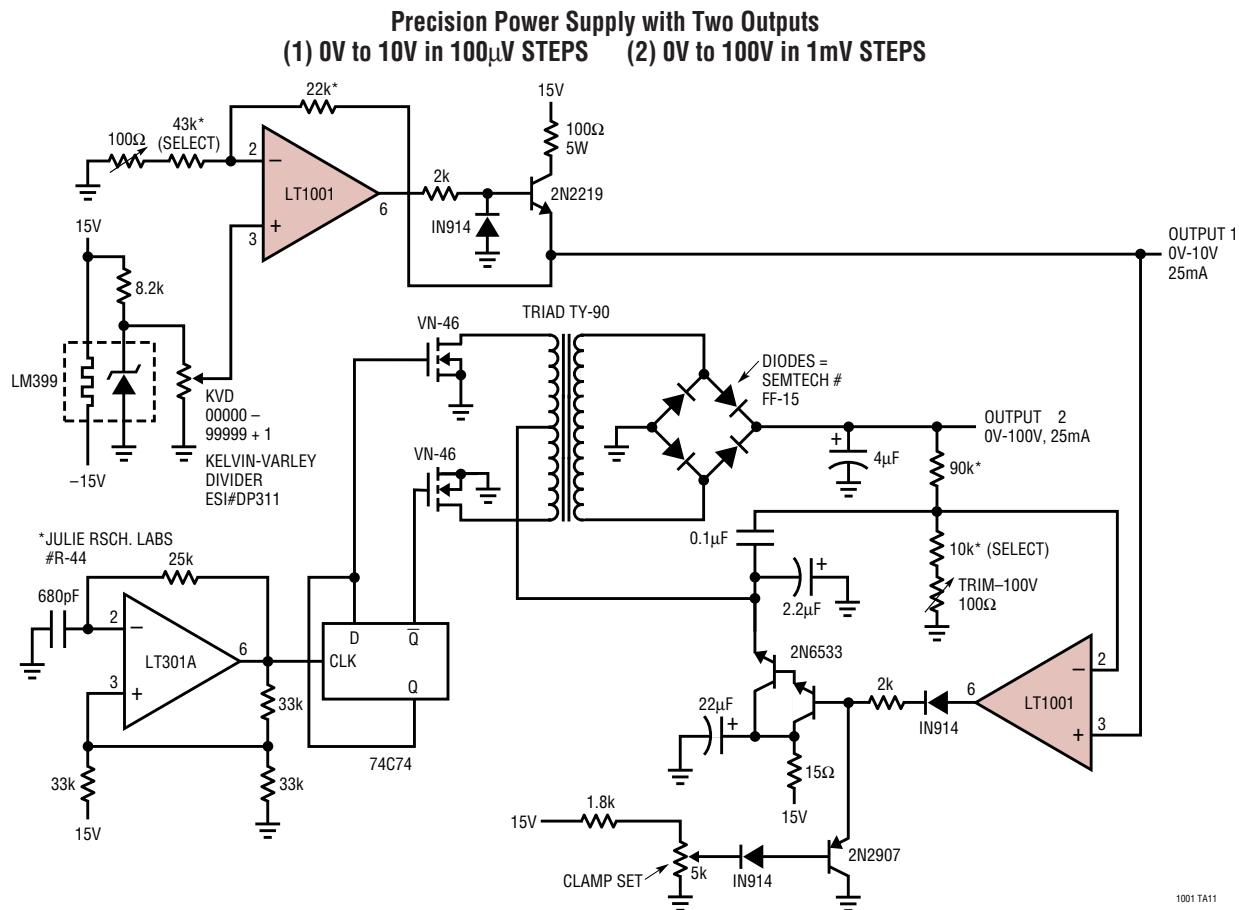
Thermally Controlled NiCad Charger



Precision Absolute Value Circuit

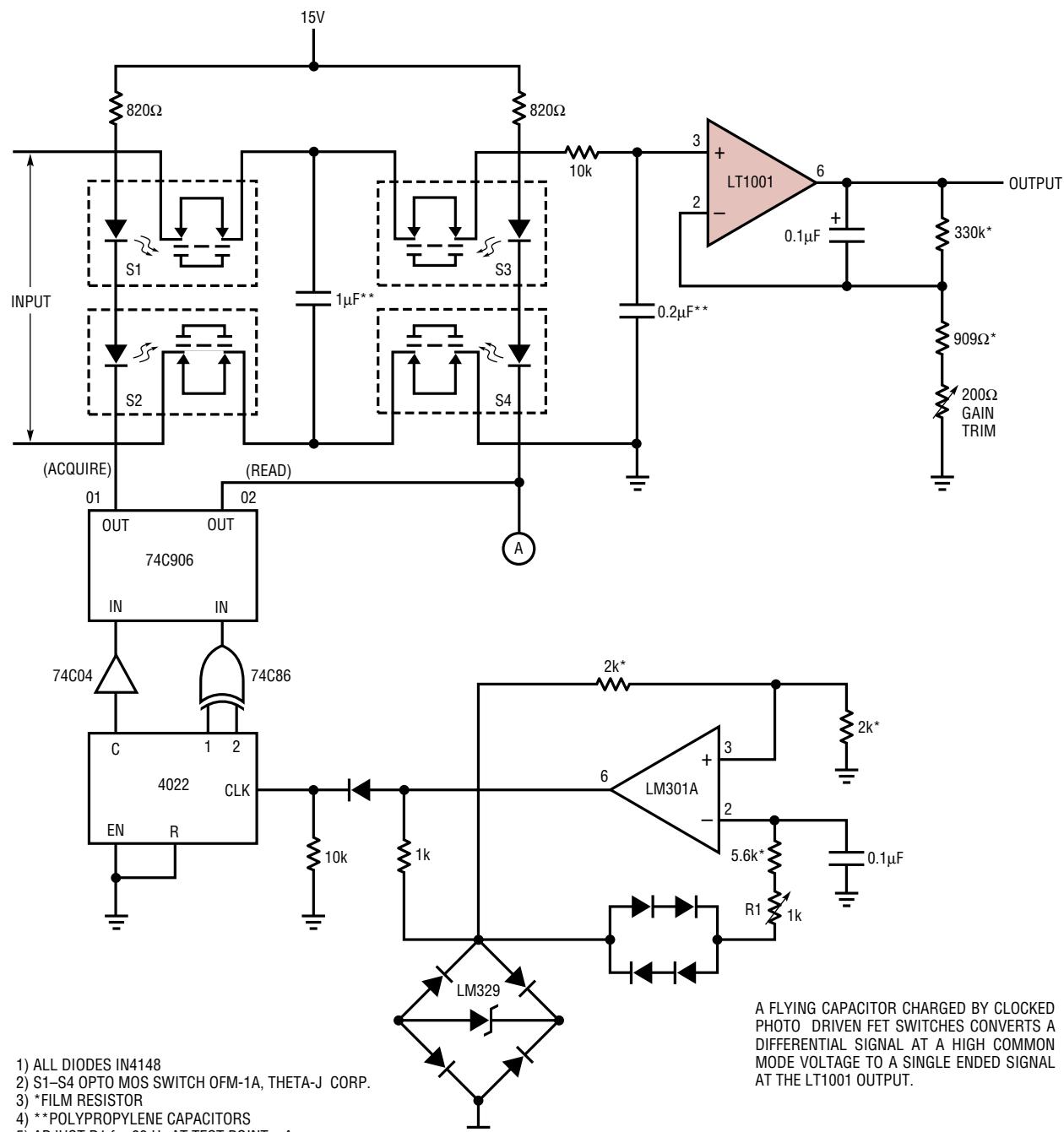


TYPICAL APPLICATIONS

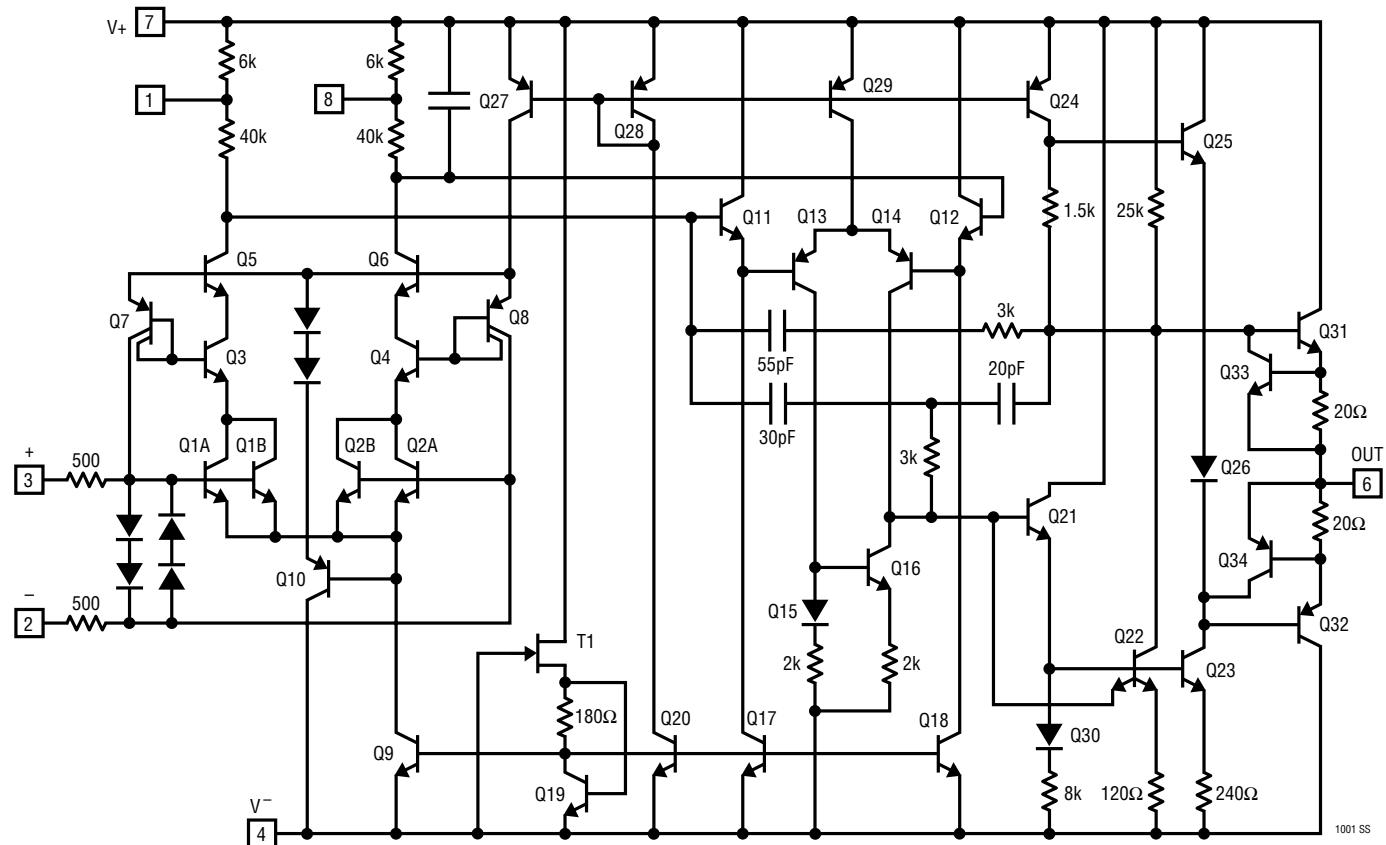


TYPICAL APPLICATIONS

Instrumentation Amplifier with $\pm 300\text{V}$
Common Mode Range and CMRR > 150dB

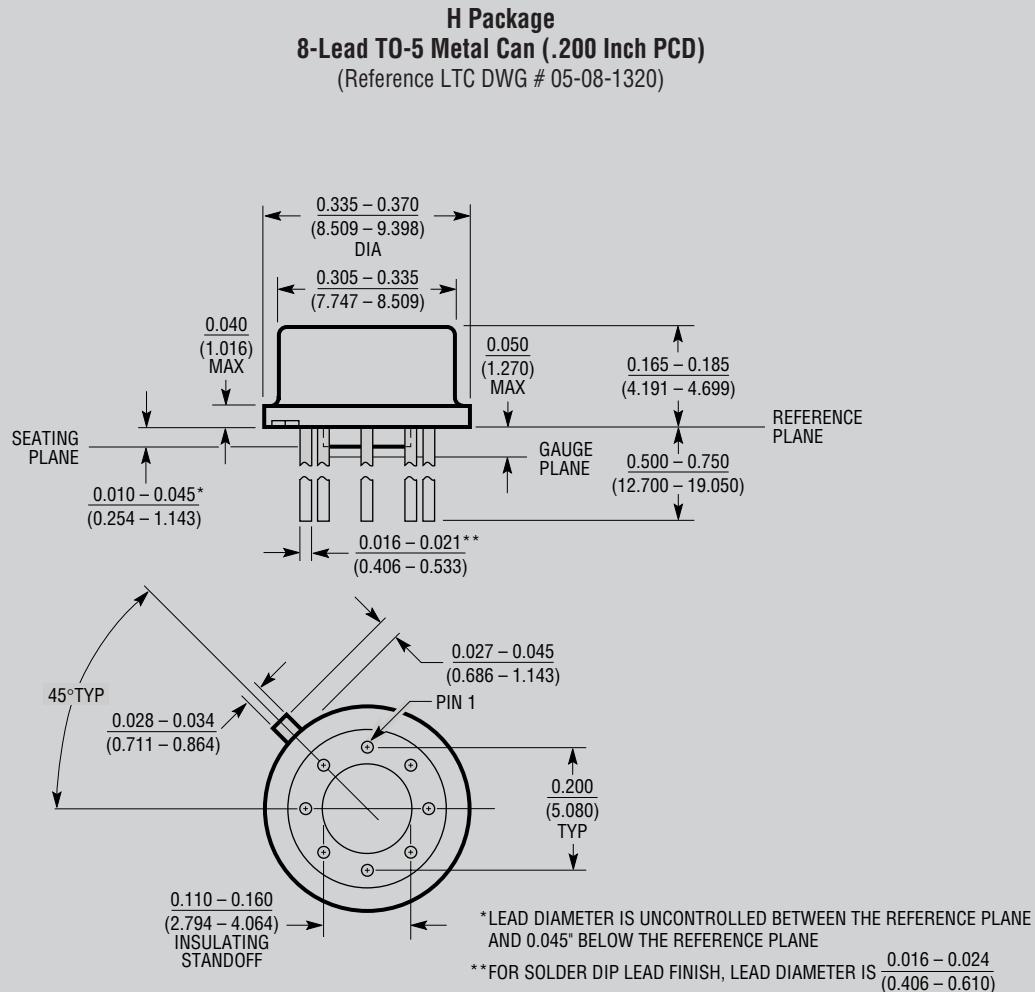


1001 TA13

SCHEMATIC DIAGRAM

1001 SS

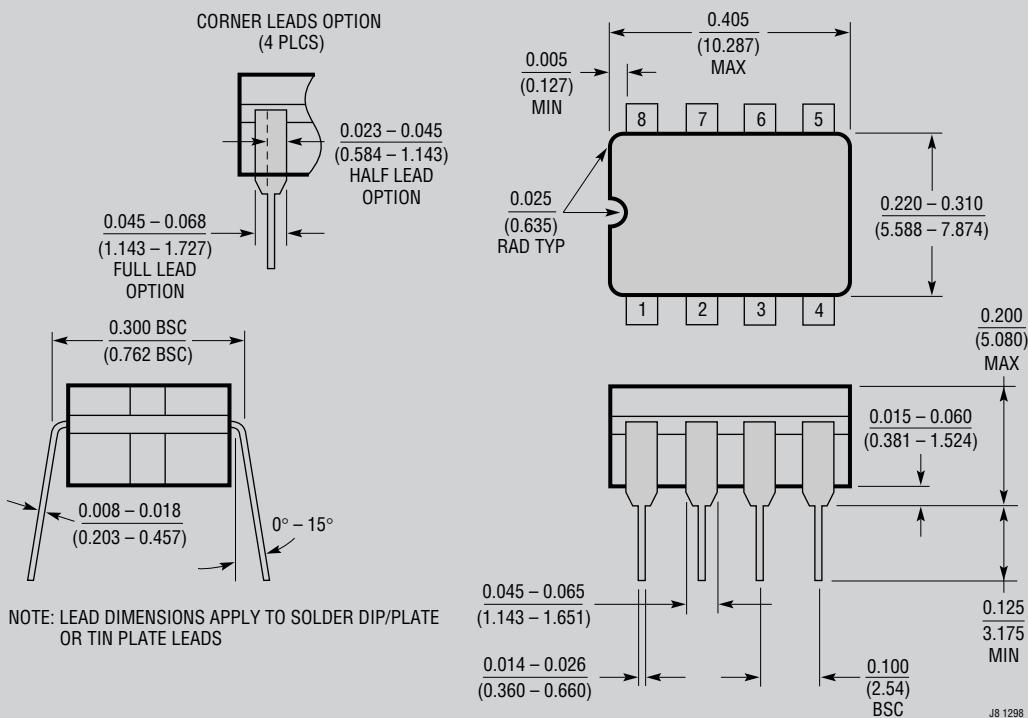
PACKAGE DESCRIPTION



OBSOLETE PACKAGE

PACKAGE DESCRIPTION

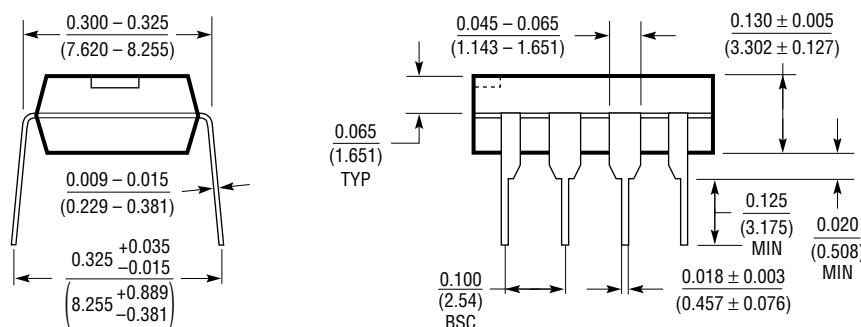
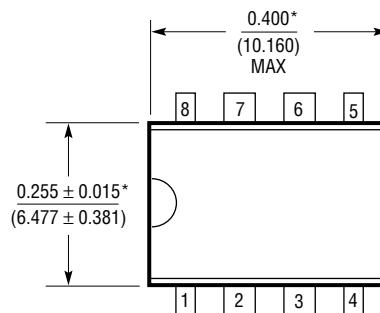
J8 Package
8-Lead CERDIP (Narrow .300 Inch, Hermetic)
 (Reference LTC DWG # 05-08-1110)



OBSOLETE PACKAGE

PACKAGE DESCRIPTION

N8 Package
8-Lead PDIP (Narrow .300 Inch)
 (Reference LTC DWG # 05-08-1510)

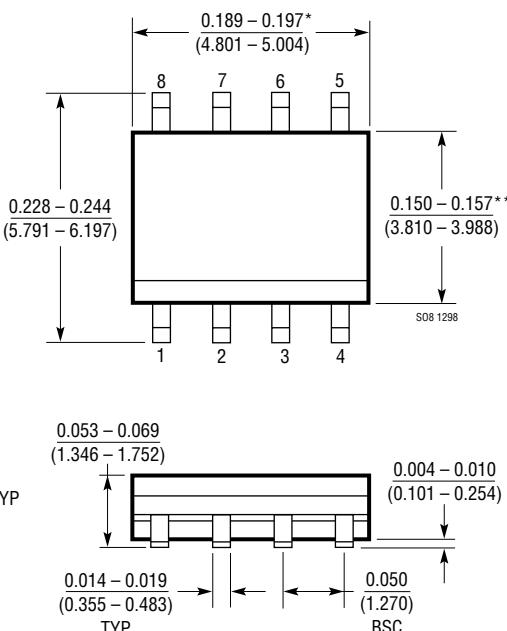


*THESE DIMENSIONS DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS.
 MOLD FLASH OR PROTRUSIONS SHALL NOT EXCEED 0.010 INCH (0.254mm)

N8 1098

PACKAGE DESCRIPTION

S8 Package
8-Lead Plastic Small Outline (Narrow .150 Inch)
 (Reference LTC DWG # 05-08-1610)



*DIMENSION DOES NOT INCLUDE MOLD FLASH. MOLD FLASH SHALL NOT EXCEED 0.006" (0.152mm) PER SIDE

**DIMENSION DOES NOT INCLUDE INTERLEAD FLASH. INTERLEAD FLASH SHALL NOT EXCEED 0.010" (0.254mm) PER SIDE